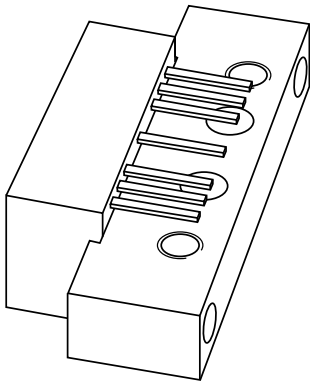


DATA SHEET



BGD712

750 MHz, 18.5 dB gain power
doubler amplifier

Product specification
Supersedes data of 2001 Oct 29

2001 Nov 02



750 MHz, 18.5 dB gain power doubler amplifier

BGD712

FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

- CATV systems operating in the 40 to 750 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2, 3	common
5	+V _B
7, 8	common
9	output

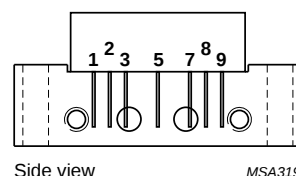


Fig.1 Simplified outline.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 45 MHz	18.2	18.8	dB
		f = 750 MHz	19	20	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	380	410	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	supply voltage	–	30	V
V _i	RF input voltage	–	70	dBmV
T _{stg}	storage temperature	–40	+100	°C
T _{mb}	operating mounting base temperature	–20	+100	°C

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CHARACTERISTICS

Bandwidth 40 to 750 MHz; $V_B = 24\text{ V}$; $T_{mb} = 35\text{ °C}$; $Z_S = Z_L = 75\ \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G_p	power gain	$f = 45\text{ MHz}$	18.2	18.5	18.8	dB
		$f = 750\text{ MHz}$	19	19.5	20	dB
SL	slope straight line	$f = 45\text{ to }750\text{ MHz}$; note 1	0.5	1	1.5	dB
FL	flatness straight line	$f = 45\text{ to }100\text{ MHz}$	–	–	± 0.35	dB
		$f = 100\text{ to }700\text{ MHz}$	–	–	± 0.5	dB
		$f = 700\text{ to }750\text{ MHz}$	–	–	± 0.15	dB
S_{11}	input return losses	$f = 45\text{ to }80\text{ MHz}$	23	–	–	dB
		$f = 80\text{ to }160\text{ MHz}$	23	–	–	dB
		$f = 160\text{ to }320\text{ MHz}$	21	–	–	dB
		$f = 320\text{ to }550\text{ MHz}$	20	–	–	dB
		$f = 550\text{ to }650\text{ MHz}$	20	–	–	dB
		$f = 650\text{ to }750\text{ MHz}$	19	–	–	dB
		$f = 750\text{ to }790\text{ MHz}$	17	–	–	dB
S_{22}	output return losses	$f = 45\text{ to }80\text{ MHz}$	23	–	–	dB
		$f = 80\text{ to }160\text{ MHz}$	23	–	–	dB
		$f = 160\text{ to }320\text{ MHz}$	20	–	–	dB
		$f = 320\text{ to }550\text{ MHz}$	20	–	–	dB
		$f = 550\text{ to }650\text{ MHz}$	19	–	–	dB
		$f = 650\text{ to }750\text{ MHz}$	19	–	–	dB
		$f = 750\text{ to }790\text{ MHz}$	17	–	–	dB
S_{21}	phase response	$f = 50\text{ MHz}$	–45	–	+45	deg
CTB	composite triple beat	112 channels flat; $V_o = 44\text{ dBmV}$; $f_m = 745.25\text{ MHz}$	–	–	–62	dB
		79 channels flat; $V_o = 44\text{ dBmV}$; $f_m = 547.25\text{ MHz}$	–	–	–68	dB
		79 channels; $f_m = 445.25\text{ MHz}$; $V_o = 49.3\text{ dBmV}$ at 547 MHz; note 2	–	–	–63	dB
X_{mod}	cross modulation	112 channels flat; $V_o = 44\text{ dBmV}$; $f_m = 55.25\text{ MHz}$	–	–	–63	dB
		79 channels flat; $V_o = 44\text{ dBmV}$; $f_m = 55.25\text{ MHz}$	–	–	–69	dB
		79 channels; $f_m = 745.25\text{ MHz}$; $V_o = 49.3\text{ dBmV}$ at 547 MHz; note 2	–	–	–60	dB

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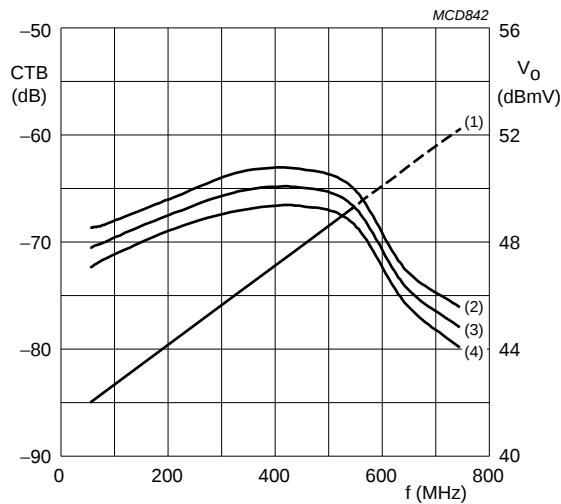
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CSO	composite second order distortion	112 channels flat; $V_o = 44$ dBmV; $f_m = 746.5$ MHz	–	–	–63	dB
		79 channels flat; $V_o = 44$ dBmV; $f_m = 548.5$ MHz	–	–	–68	dB
		79 channels; $f_m = 746.5$ MHz; $V_o = 49.3$ dBmV at 547 MHz; note 2	–	–	–62	dB
d_2	second order distortion	note 3	–	–	–74	dB
V_o	output voltage	$d_{im} = -60$ dB; note 4	64	–	–	dBmV
NF	noise figure	$f = 50$ MHz	–	–	5.5	dB
		$f = 550$ MHz	–	–	5.5	dB
		$f = 750$ MHz	–	–	7	dB
I_{tot}	total current consumption (DC)	note 5	380	395	410	mA

Notes

- Slope straight line is defined as gain at 750 MHz – gain at 45 MHz.
- Tilt = 7.3 dB (55 to 547 MHz).
- $f_p = 55.25$ MHz; $V_p = 44$ dBmV;
 $f_q = 691.25$ MHz; $V_q = 44$ dBmV;
measured at $f_p + f_q = 746.5$ MHz.
- Measured according to DIN45004B:
 $f_p = 740.25$ MHz; $V_p = V_o$;
 $f_q = 747.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 749.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 738.25$ MHz.
- The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

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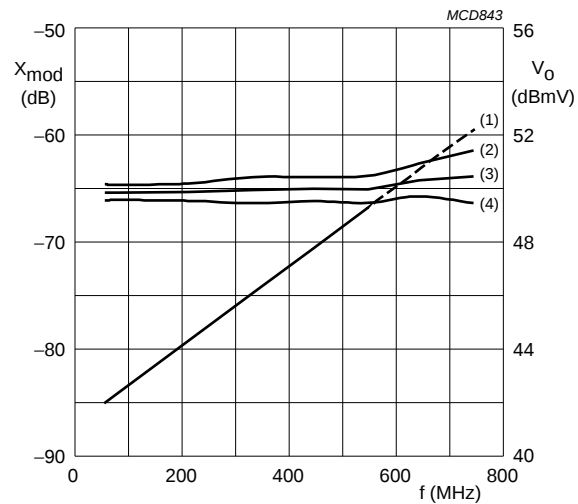
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$Z_S = Z_L = 75 \Omega$; $V_B = 24 \text{ V}$; 79 channels;
tilt = 7.3 dB (50 to 550 MHz).

- (1) V_O . (3) Typ.
(2) Typ. +3 σ . (4) Typ. -3 σ .

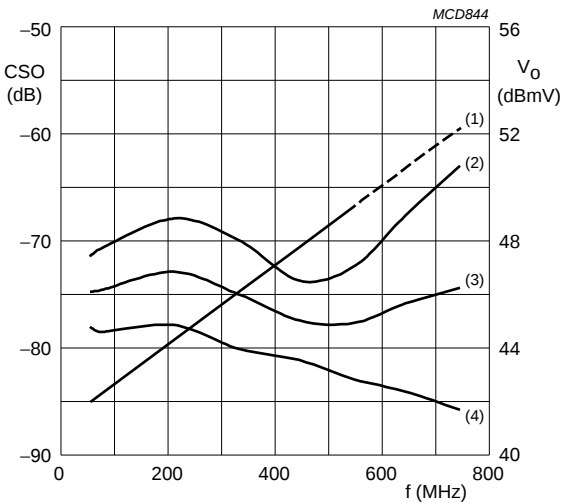
Fig.2 Composite triple beat as a function of frequency under tilted conditions.



$Z_S = Z_L = 75 \Omega$; $V_B = 24 \text{ V}$; 79 channels;
tilt = 7.3 dB (50 to 550 MHz).

- (1) V_O . (3) Typ.
(2) Typ. +3 σ . (4) Typ. -3 σ .

Fig.3 Cross modulation as a function of frequency under tilted conditions.



$Z_S = Z_L = 75 \Omega$; $V_B = 24 \text{ V}$; 79 channels;
tilt = 7.3 dB (50 to 550 MHz).

- (1) V_O . (3) Typ.
(2) Typ. +3 σ . (4) Typ. -3 σ .

Fig.4 Composite second order distortion as a function of frequency under tilted conditions.

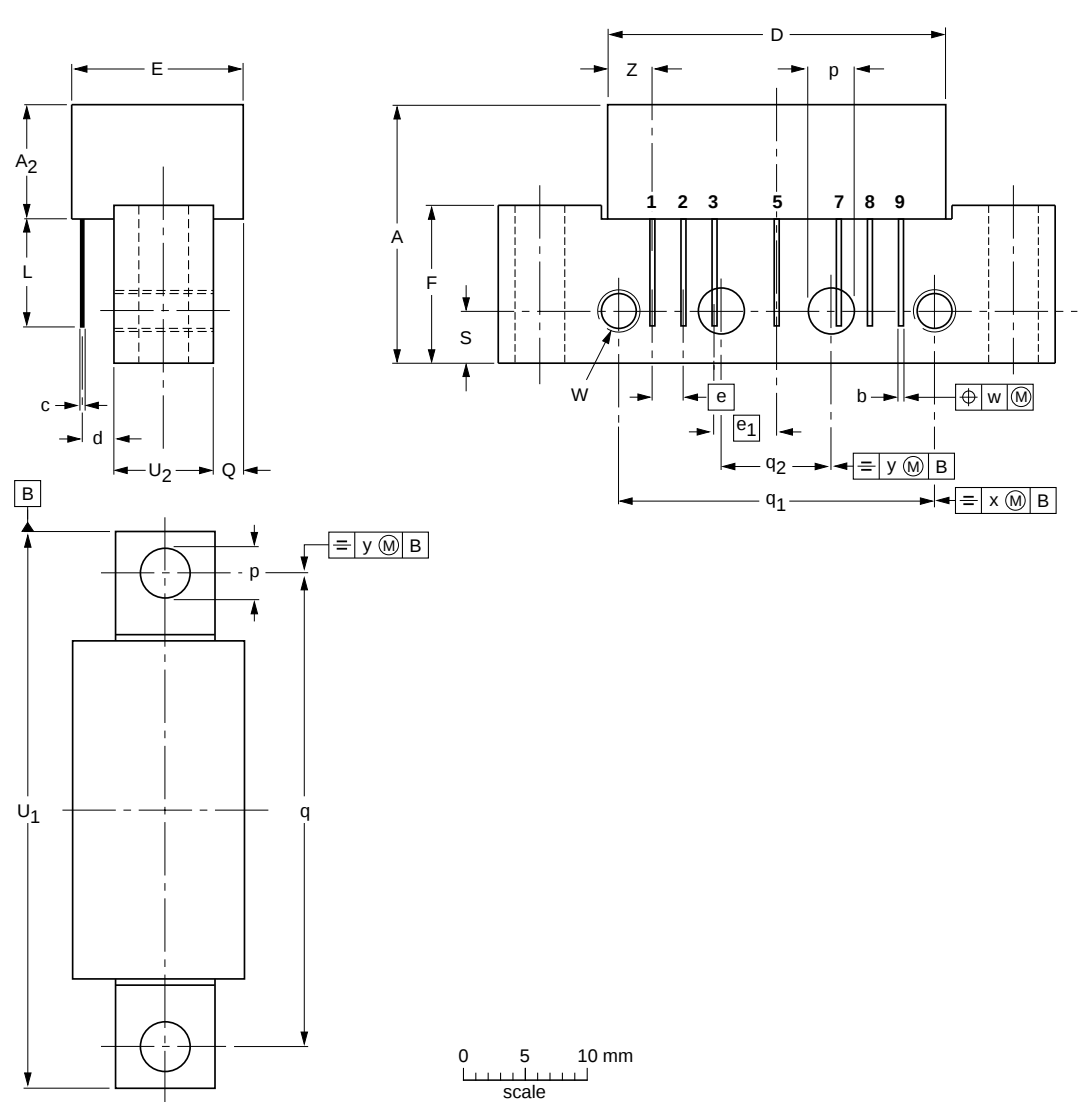
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PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes;
2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₂ max.	b	c	D max.	d	E max.	e	e ₁	F	L min.	p	Q max.	q	q ₁	q ₂	S	U ₁	U ₂	W	w	x	y	Z max.
mm	20.8	9.5	0.51 0.38	0.25	27.2	2.04 2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75 44.25	8.2 7.8	6-32 UNC	0.25	0.7	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT115J						04-02-04 10-06-18

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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